

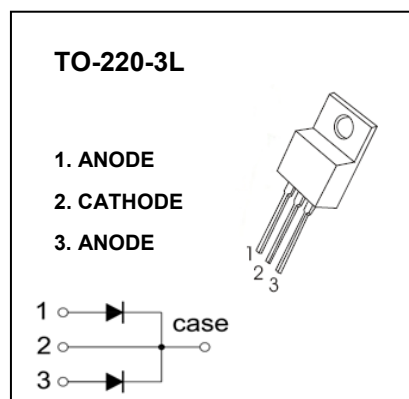
TO-220-3L Plastic-Encapsulate Diodes

SBL3030CT, 35CT, 40CT, 45CT, 50CT, 60CT

SCHOTTKY BARRIER RECTIFIER

FEATURES

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value						Unit
		SBL 3030CT	SBL 3035CT	SBL 3040CT	SBL 3045CT	SBL 3050CT	SBL 3060CT	
V_{RRM}	Peak repetitive reverse voltage	30	35	40	45	50	60	V
V_{RWM}	Working peak reverse voltage							
V_R	DC blocking voltage							
$V_{R(RMS)}$	RMS reverse voltage	21	24.5	28	31.5	35	42	V
I_O	Average rectified output current@ $T_c=100^\circ\text{C}$	30						A
I_{FSM}	Non-Repetitive peak forward surge current 8.3ms half sine wave	250						A
P_D	Power dissipation	2						W
$R_{\theta JA}$	Thermal resistance from junction to ambient	50						$^\circ\text{C}/\text{W}$
T_j	Junction temperature	125						$^\circ\text{C}$
T_{stg}	Storage temperature	-55~+150						$^\circ\text{C}$



ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Device	Test conditions	Min	Typ	Max	Unit
Reverse voltage	V _(BR)	SBL3030CT	I _R =1mA	30			V
		SBL3035CT		35			
		SBL3040CT		40			
		SBL3045CT		45			
		SBL3050CT		50			
		SBL3060CT		60			
Reverse current	I _R	SBL3030CT	V _R =30V			1	mA
		SBL3035CT	V _R =35V				
		SBL3040CT	V _R =40V				
		SBL3045CT	V _R =45V				
		SBL3050CT	V _R =50V				
		SBL3060CT	V _R =60V				
Forward voltage	V _F	SBL3030CT-3045CT	I _F =15A			0.55	V
		SBL3050CT,3060CT				0.7	
Typical total capacitance	C _{tot}	SBL3030CT-3060CT	V _R =4V,f=1MHz		420		pF